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# 74VHC4316 **Quad Analog Switch with Level Translator**

#### **Features**

- Typical switch enable time: 20ns
- Wide analog input voltage range: ±6V
- Low "ON" resistance: 50 Typ. (V<sub>CC</sub>-V<sub>EE</sub> = 4.5V) 30 Typ.  $(V_{CC}-V_{EE} = 9V)$
- Low guiescent current: 80µA maximum (74VHC)
- Matched switch characteristics
- Individual switch controls plus a common enable
- Pin functional compatible with 74HC4316

## **General Description**

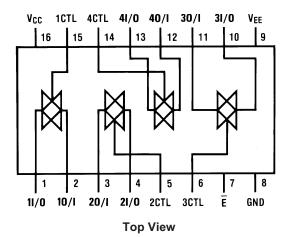
These devices are digitally controlled analog switches implemented in advanced silicon-gate CMOS technology. These switches have low "ON" resistance and low "OFF" leakages. They are bidirectional switches, thus any analog input may be used as an output and viceversa. Three supply pins are provided on the 4316 to implement a level translator which enables this circuit to operate with 0V-6V logic levels and up to ±6V analog switch levels. The 4316 also has a common enable input in addition to each switch's control which when HIGH will disable all switches to their off state. All analog inputs and outputs and digital inputs are protected from electrostatic damage by diodes to V<sub>CC</sub> and ground.

## **Ordering Information**

Order Number	Package Number	Package Description
74VHC4316M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VHC4316WM	M16B	16-Lead Small Outline Intergrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VHC4316MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering number.

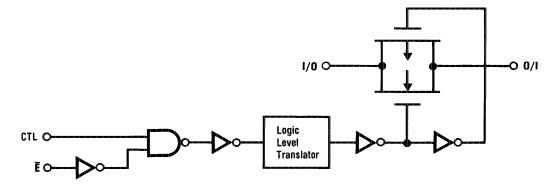
## **Connection Diagram**



### **Truth Table**

Inp	outs	Switch			
Ē	CTL	I/O-O/I			
Н	Х	"OFF"			
L	L	"OFF"			
L	Н	"ON"			

# **Logic Diagram**



## Absolute Maximum Ratings<sup>(1)</sup>

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V <sub>CC</sub>	Supply Voltage	-0.5 to +7.5V
V <sub>EE</sub>	Supply Voltage	+0.5 to -7.5V
V <sub>IN</sub>	DC Control Input Voltage	-1.5 to V <sub>CC</sub> +1.5V
V <sub>IO</sub>	DC Switch I/O Voltage	V <sub>EE</sub> -0.5 to V <sub>CC</sub> +0.5V
I <sub>IK</sub> , I <sub>OK</sub>	Clamp Diode Current	
I <sub>OUT</sub>	DC Output Current, per pin	
I <sub>cc</sub>	DC V <sub>CC</sub> or GND Current, per pin	
T <sub>STG</sub>	Storage Temperature Range	–65°C to +150°C
P <sub>D</sub>	Power Dissipation	600mW
	S.O. Package only	500mW
T <sub>L</sub>	Lead Temperature (Soldering 10 seconds)	260°C

#### Note:

1. Unless otherwise specified all voltages are referenced to ground.

## **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Units
V <sub>CC</sub>	Supply Voltage	2	6	V
V <sub>EE</sub>	Supply Voltage	0	-6	V
V <sub>IN</sub> , V <sub>OUT</sub>	DC Input or Output Voltage	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature Range	-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Times			
	V <sub>CC</sub> = 2.0V		1000	ns
	$V_{CC} = 4.5V$		500	
	$V_{CC} = 6.0V$ $V_{CC} = 12.0V$		400	
	V <sub>CC</sub> = 12.0V		250	

## DC Electrical Characteristics<sup>(2)</sup>

					1 1 -		T <sub>A</sub> = -40°C to +85°C	
Symbol	Parameter	Conditions	V <sub>EE</sub>	V <sub>CC</sub>	Тур.	Guara	nteed Limits	Units
V <sub>IH</sub>	Minimum HIGH Level			2.0V		1.5	1.5	V
	Input Voltage			4.5V		3.15	3.15	
				6.0V		4.2	4.2	
V <sub>IL</sub>	Maximum LOW Level			2.0V		0.5	0.5	V
	Input Voltage			4.5V		1.35	1.35	
				6.0V		1.8	1.8	
R <sub>ON</sub>	Minimum "ON"	$V_{CTL} = V_{IH},$	GND	4.5V	100	170	200	Ω
	Resistance <sup>(3)</sup>	$I_S = 2.0 \text{mA},$	-4.5V	4.5V	40	85	105	
		$V_{IS} = V_{CC}$ to $V_{EE}$ , (Fig. 1)	-6.0V	6.0V	30	70	85	
		$V_{CTL} = V_{IH},$	GND	2.0V	100	180	215	
		$I_S = 2.0 \text{mA},$	GND	4.5V	40	80	100	
		$V_{IS} = V_{CC}$ or $V_{EE}$ (Fig. 1)	-4.5V	4.5V	50	60	75	
		(1 19. 1)	-6.0V	6.0V	20	40	60	
R <sub>ON</sub>	Maximum "ON"	$V_{CTL} = V_{IH},$ $V_{IS} = V_{CC}$ to $V_{EE}$	GND	4.5V	10	15	20	Ω
	Resistance Matching		-4.5V	4.5V	5	10	15	
			-6.0V	6.0V	5	10	15	
I <sub>IN</sub>	Maximum Control Input Current	$V_{IN} = V_{CC}$ or GND	GND	6.0V		±0.1	±1.0	μA
I <sub>IZ</sub>	Maximum Switch "OFF"	$V_{OS} = V_{CC}$ or $V_{EE}$ ,	GND	6.0V		±30	±300	nA
	Leakage Current	$V_{IS} = V_{EE} \text{ or } V_{CC},$ $V_{CTL} = V_{IL} \text{ (Fig. 2)}$	-6.0V	6.0V		±50	±500	
I <sub>IZ</sub>	Maximum Switch "ON"	$V_{IS} = V_{CC}$ to $V_{EE}$ ,	GND	6.0V		±20	±75	nA
	Leakage Current	$V_{CTL} = V_{IH},$ $V_{OS} = OPEN$ (Fig. 3)	-6.0V	6.0V		±30	±150	
I <sub>CC</sub>	Maximum Quiescent	$V_{IN} = V_{CC}$ or GND,	GND	6.0V		1.0	10	μA
	Supply Current	$I_{OUT} = 0 \mu A$	-6.0V	6.0V		4.0	40	

#### Notes:

- 2. For a power supply of 5V  $\pm 10\%$  the worst case on resistances (R<sub>ON</sub>) occurs for VHC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V<sub>IH</sub> and V<sub>IL</sub> occur at V<sub>CC</sub> = 5.5V and 4.5V respectively. (The V<sub>IH</sub> value at 5.5V is 3.85V.) The worst case leakage current occurs for CMOS at the higher voltage and so the 5.5V values should be used.
- 3. At supply voltages (V<sub>CC</sub>-V<sub>EE</sub>) approaching 2V the analog switch on resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital only when using these supply voltages.

## **AC Electrical Characteristics**

 $\rm V_{CC} = 2.0V - 6.0V, \, V_{EE} = 0V - 6V, \, C_L = 50 \, \, pF$  unless otherwise specified

					T <sub>A</sub> = -	+25°C	T <sub>A</sub> = -40°C to +85°C	
Symbol	Parameter	Conditions	$V_{EE}$	V <sub>CC</sub>	Тур.	Guarai	nteed Limits	Units
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation		GND	3.3V	15	30	37	ns
	Delay Switch In to Out		GND	4.5V	5	10	13	
			-4.5V	4.5V	4	8	12	
			-6.0V	6.0V	3	7	11	
t <sub>PZL</sub> , t <sub>PZH</sub>	Maximum Switch Turn	$R_L = 1k\Omega$	GND	3.3V	25	97	120	ns
	"ON" Delay (Control)		GND	4.5V	20	35	43	
			-4.5V	4.5V	15	32	39	
			-6.0V	6.0V	14	30	37	
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Maximum Switch Turn	$R_L = 1 k\Omega$	GND	3.3V	35	145	180	ns
	"OFF" Delay (Control)		GND	4.5V	25	50	63	
			-4.5V	4.5V	20	44	55	
			-6.0V	6.0V	20	44	55	
t <sub>PZL</sub> , t <sub>PZH</sub>	Maximum Switch Turn		GND	3.3V	27	120	150	ns
	"ON" Delay (Enable)		GND	4.5V	20	41	52	
			-4.5V	4.5V	19	38	48	
			-6.0V	6.0V	18	36	45	
t <sub>PLZ</sub> , t <sub>PHZ</sub>	Maximum Switch Turn "OFF" Delay (Enable)		GND	3.3V	42	155	190	ns
			GND	4.5V	28	53	67	
			-4.5V	4.5V	23	47	59	
			-6.0V	6.0V	21	47	59	
	Minimum Frequency	$R_L = 600\Omega$ ,	0V	4.5	40			MHz
	Response (Fig. 7) 20 log (V <sub>OS</sub> /V <sub>IS</sub> )= –3 dB	$V_{IS} = 2V_{PP} \text{ at}$ $(V_{CC} - V_{EE}/2)^{(4)(5)}$	-4.5V	4.5V	100			
	Control to Switch	$R_L = 600\Omega$ , $f = 1MHz$	0V	4.5V	100			mV
	Feedthrough Noise (Fig. 8)	$C_L = 50pF^{(5)(6)}$	-4.5V	4.5V	250			
	Crosstalk Between any	$R_L = 600\Omega$ , $f = 1MHz$	0V	4.5V	-52			dB
	Two Switches (Fig. 9)		-4.5V	4.5V	-50			
	Switch OFF Signal	$R_L = 600\Omega$ ,	0V	4.5V	-42			dB
	Feedthrough Isolation (Fig. 10)	f = 1MHz, $V_{CTL} = V_{IL}^{(5)(6)}$	–4.5V	4.5V	-44			
THD	Sinewave Harmonic Distortion	$\label{eq:local_local_local_local_local} \begin{split} R_L &= 10 \text{ K}\Omega, \\ C_L &= 50 \text{ pF, f} = 1 \text{KHz} \\ V_{IS} &= 4 \text{ V}_{PP} \\ V_{IS} &= 8 \text{ V}_{PP} \end{split}$	0V -4.5V	4.5V 4.5V	0.013			%
C <sub>IN</sub>	Maximum Control Input Capacitance	13 - 14	1.0 0	1.01	5			pF
C <sub>IN</sub>	Maximum Switch Input Capacitance				35			pF
C <sub>IN</sub>	Maximum Feedthrough Capacitance	V <sub>CTL</sub> = GND			0.5			pF
C <sub>PD</sub>	Power Dissipation Capacitance				15			pF

- 4. Adjust 0 dBm for f = 1 kHz (Null  $R_L/Ron$  Attenuation).
- 5. V<sub>IS</sub> is centered at V<sub>CC</sub>-V<sub>EE</sub>/2.
  6. Adjust for 0 dBm.

## **AC Test Circuits and Switching Time Waveforms**

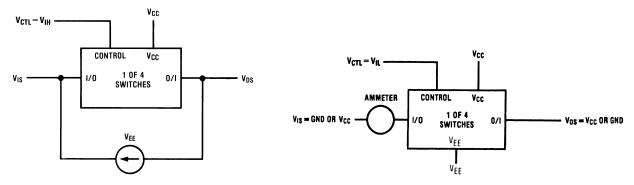


Figure 1. "ON" Resistance

Figure 2. "OFF" Channel Leakage Current

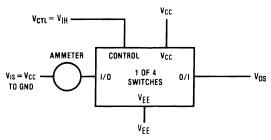


Figure 3. "ON" Channel Leakage Current



Figure 4.  $t_{PHL}$ ,  $t_{PLH}$  Propagation Delay Time Signal Input to Signal Output

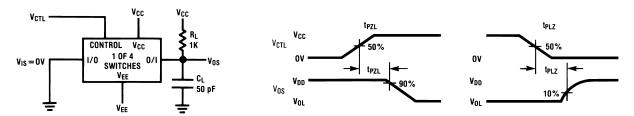


Figure 5. t<sub>PZL</sub>, t<sub>PLZ</sub> Propagation Delay Time Control to Signal Output

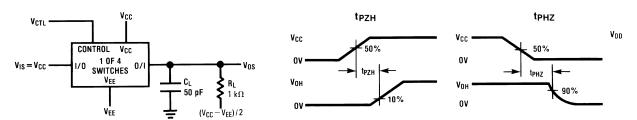


Figure 6. t<sub>PZH</sub>, t<sub>PHZ</sub> Propagation Delay Time Control to Signal Output

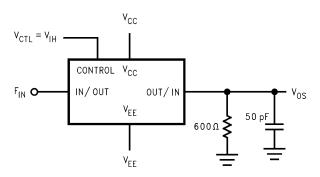


Figure 7. Frequency Response

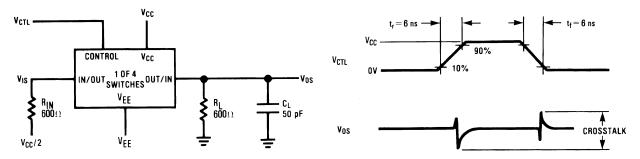


Figure 8. Crosstalk: Control Input to Signal Output

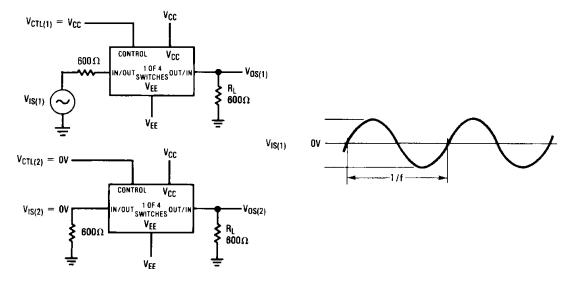


Figure 9. Crosstalk Between Any Two Switches

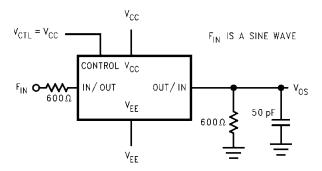


Figure 10. Switch OFF Signal Feedthrough Isolation

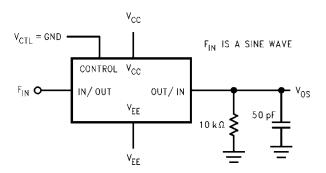
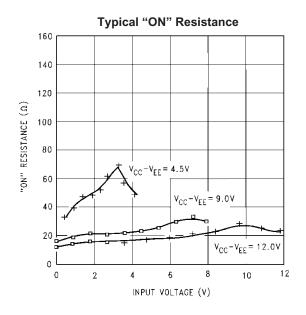
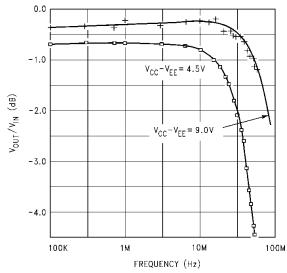


Figure 11. Sinewave Distortion

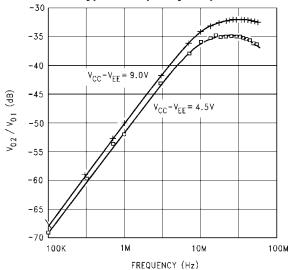
## **Typical Performance Characteristics**



# Typical Crosstalk Between Any Two Switches





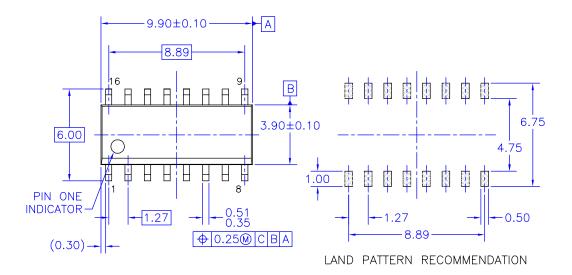


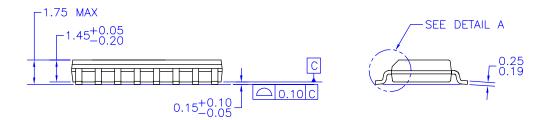
## **Special Considerations**

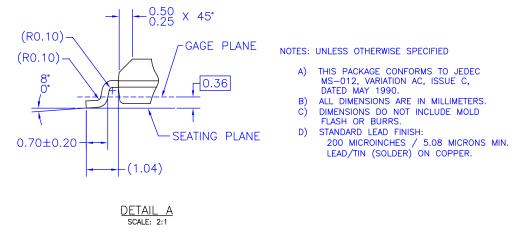
In certain applications the external load-resistor current may include both  $V_{CC}$  and signal line components. To avoid drawing  $V_{CC}$  current when switch current flows into the analog switch input pins, the voltage drop across the switch must not exceed 0.6V (calculated from the ON resistance).

## **Physical Dimensions**

Dimensions are in millimeters unless otherwise noted.







M16AREVK

Figure 12. 16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Package Number M16A

## Physical Dimensions (Continued)

Dimensions are in inches (millimeters) unless otherwise noted.

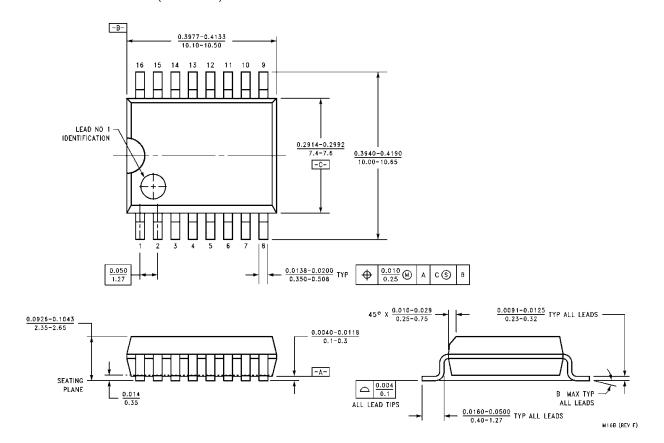


Figure 13. 16-Lead Small Outline Intergrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Package Number M16B

## Physical Dimensions (Continued) Dimensions are in millimeters unless otherwise noted. Α 5.00±0.10 4.55 5.90 4.45 7.35 В 6.4 0.65 4.4±0.1 3.2 O.2 CBA ALL LEAD TIPS 5.00 PIN #1 IDENT. LAND PATTERN RECOMMENDATION (F) 0.11-SEE DETAIL A ALL LEAD TIPS (0.90) 1.1 MAX ○ 0.1 C 0.09-0.20 -C-0.10±0.05 0.65 0.19 - 0.30 TOP AND BOTTOM **♦ 0.10** A B C C S GAGE PLANE NOTES: 0.25 0°-8°

- A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB,
- **B. DIMENSIONS ARE IN MILLIMETERS**
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS
- D. DIMENSIONING AND TOLERANCES PER ANSI Y14.5M, 1994
- E. DRAWING FILE NAME: MTC16REV4
- F. LAND PATTERN RECOMMENDATION PER IPC7351 ID# TSOP65P640X110-16N

MTC16rev4

Figure 14. 16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC16

0.6±0.1

**DETAIL** A

SEATING PLANE





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